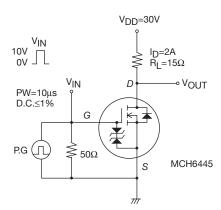
MCH6445

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
Parameter		Conditions	min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	I _D =1mA, V _G S=0V	60			V
Zero-Gate Voltage Drain Current	IDSS	VDS=60V, VGS=0V			1	μΑ
Gate-to-Source Leakage Current	IGSS	V _{GS} =±16V, V _{DS} =0V			±10	μΑ
Cutoff Voltage	V _{GS} (off)	V _{DS} =10V, I _D =1mA	1.2		2.6	V
Forward Transfer Admittance	yfs	V _{DS} =10V, I _D =2A		3		S
Static Drain-to-Source On-State Resistance	RDS(on)1	ID=2A, VGS=10V		60	78	mΩ
	R _{DS} (on)2	I _D =1A, V _G S=4.5V		74	104	mΩ
	R _{DS} (on)3	I _D =1A, V _G S=4V		81	114	mΩ
Input Capacitance	Ciss			505		pF
Output Capacitance	Coss	V _{DS} =20V, f=1MHz		57		pF
Reverse Transfer Capacitance	Crss			37		рF
Turn-ON Delay Time	t _d (on)			7.3		ns
Rise Time	tr	One are alifted Took Circuit		9.8		ns
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit.		40		ns
Fall Time	tf			24		ns
Total Gate Charge	Qg			10		nC
Gate-to-Source Charge	Qgs	V _{DS} =30V, V _{GS} =10V, I _D =4A		1.6		nC
Gate-to-Drain "Miller" Charge	Qgd	1		2.1		nC
Diode Forward Voltage	V _{SD}	I _S =4A, V _{GS} =0V		0.82	1.2	V

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

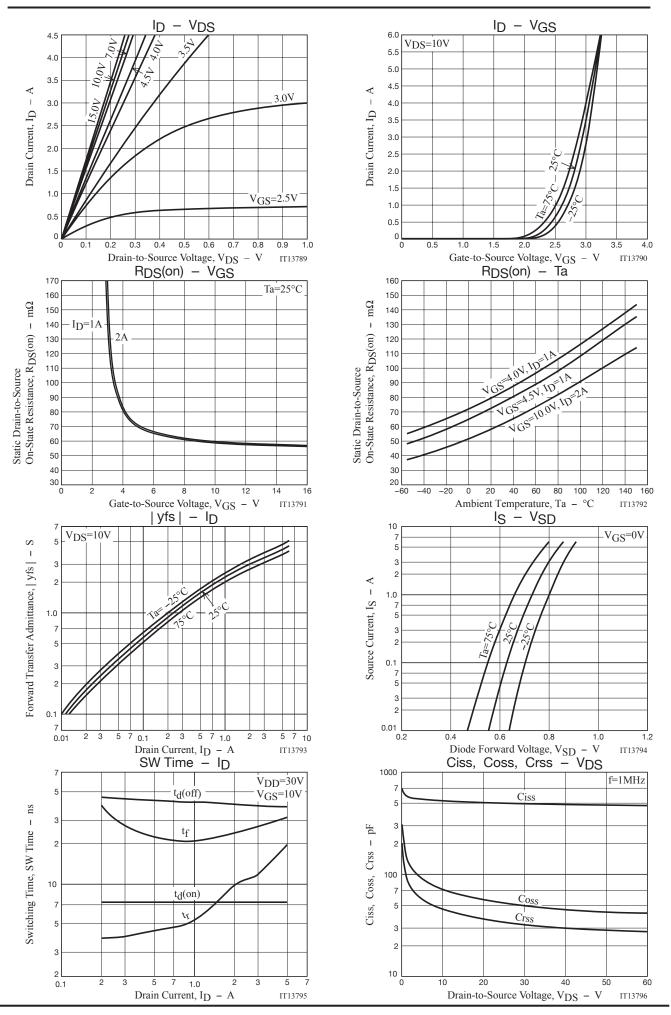
Switching Time Test Circuit



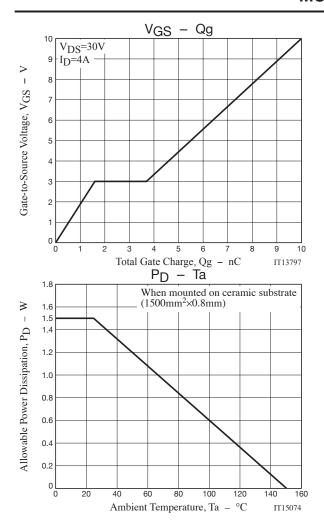
Ordering Information

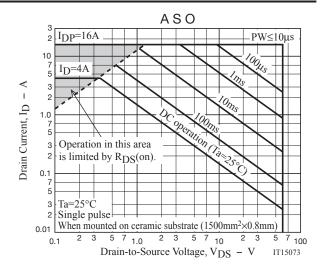
Device	Package	Shipping	memo	
MCH6445-TL-E	MCPH6	3.000pcs./reel	Pb-Free	
MCH6445-TL-W	MCPH6	3,000pcs./reei	Pb-Free and Halogen Free	

No. A1566-2/5



MCH6445

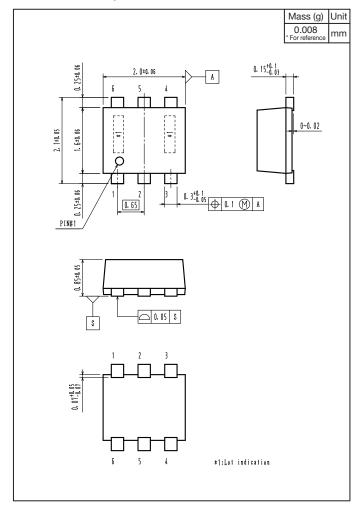


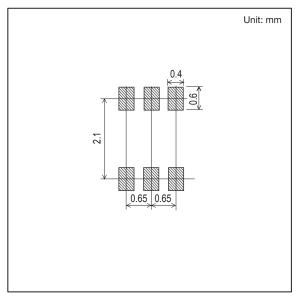


Outline Drawing

MCH6445-TL-E, MCH6445-TL-W

Land Pattern Example





Note on usage: Since the MCH6445 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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